NSN 5961-01-195-1015

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-195-1015 **Inclosure Material:** Metal **Overall Length:** 1.519 inches **Overall Height:** 1.080 inches **Overall Width:** 0.450 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 8.00 amperes source cutoff current **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 2 unthreaded hole and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

Fiig:

A110a0